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			Application Number	Unknown	
			Filing Date	Herewith	
			First Named Inventor	Mark Lemkin	
			Group Art Unit	Unknown	
			Examiner Name	Unknown	
			Attorney Docket Number	AIMI-01841US0	
Sheet	1	of	2		

[illegible][illegible]

Examiner Signature		Date Considered	1/16/03
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PTO/SB/08B (08-00)

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				Filing Date	Herewith
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				Attorney Docket Number	AIMI-01841US0

OTHER PRIOR ART – NON PATENT LITERATURE DOCUMENTS			
Examiner Initials <sup>*</sup>	Cite No. <sup>1</sup>	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T <sup>2</sup>
ah		DELEONIBUS, S., et al., "Field Transistors Electrical Behaviour in Double Level Aluminum Interconnect Processe VLSI Multilevel Interconnection Conference, 1989, 6th Int'l IEEE, 1989, p. 507	
		DALE, D.P.E., "Video Amplifiers for Video Display Units", Linear Analogue Circuits and Systems, IEE Colloquium in 1992, pp. 8/1-8/7	
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		MEYER, W.G., et al., "Integrable High Voltage CMOS: Devices, Process Application", 1985 IEEE, IEDM 85, pp. 732-735	

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